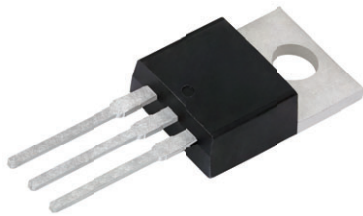


High Performance Schottky Rectifier, 2 x 30 A


3L TO-220AB


FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
V_R	30 V
V_F at I_F	0.44 V
I_{RM} max.	350 mA at 125 °C
T_J max.	150 °C
E_{AS}	13 mJ
Package	3L TO-220AB
Circuit configuration	Common cathode

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform (per device)	60	A
V_{RRM}		30	V
I_{FRM}	$T_C = 120$ °C (per leg)	60	A
I_{FSM}	$t_p = 5$ μ s sine	1500	
V_F	30 A _{pk} , $T_J = 125$ °C	0.44	V
T_J	Range	-65 to +150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-62CTQ030-M3	UNITS
Maximum DC reverse voltage	V_R	30	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current per leg per device	$I_{F(AV)}$	50 % duty cycle at $T_C = 120$ °C, rectangular waveform	30	A
			60	
Peak repetitive forward current per leg	I_{FRM}	Rated V_R , square wave, 20 kHz, $T_C = 127$ °C	60	
Maximum peak one cycle non-repetitive surge current per leg	I_{FSM}	5 μ s sine or 3 μ s rect. pulse	1500	
		10 ms sine or 6 ms rect. pulse	300	
Non-repetitive avalanche energy per leg	E_{AS}	$T_J = 25$ °C, $I_{AS} = 3$ A, $L = 2.9$ mH	13	mJ
Repetitive avalanche current per leg	I_{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	3	A



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS	
Maximum forward voltage drop	$V_{FM}^{(1)}$	30 A	$T_J = 25\text{ }^\circ\text{C}$	0.46	0.5	V
		60 A		0.56	0.6	
		30 A	$T_J = 125\text{ }^\circ\text{C}$	0.39	0.44	
		60 A		0.54	0.59	
Maximum instantaneous reverse current	I_{RM}	$T_J = 25\text{ }^\circ\text{C}$	Rated DC voltage	0.4	2.5	mA
		$T_J = 125\text{ }^\circ\text{C}$		180	350	
Maximum junction capacitance	C_T	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$	3000		pF	
Typical series inductance	L_S	Measured from top of terminal to mounting plane	8.0		nH	
Maximum voltage rate of change	dV/dt	Rated V_R	10 000		V/ μs	

Note(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T_J		-65 to +150	$^\circ\text{C}$
Maximum storage temperature range	T_{Stg}		-65 to +175	
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation	1.2	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum	Non-lubricated threads	6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style 3L TO-220AB	62CTQ030	

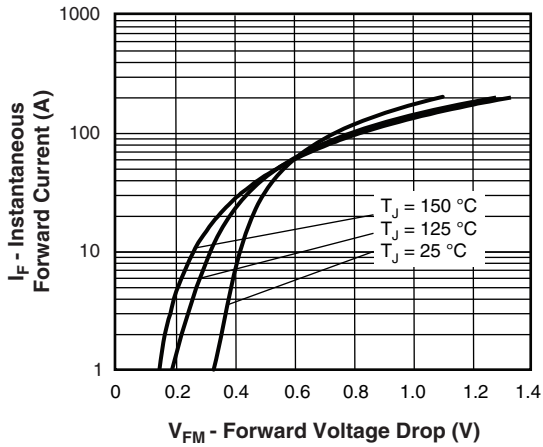


Fig. 1 - Maximum Forward Voltage Drop Characteristics

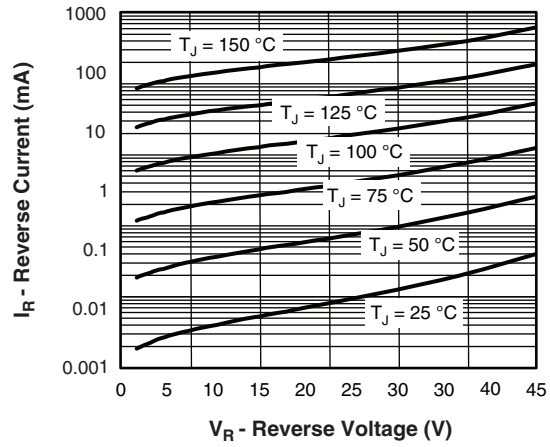


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

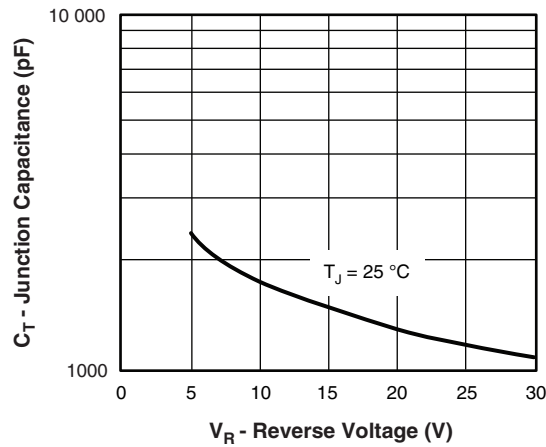


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

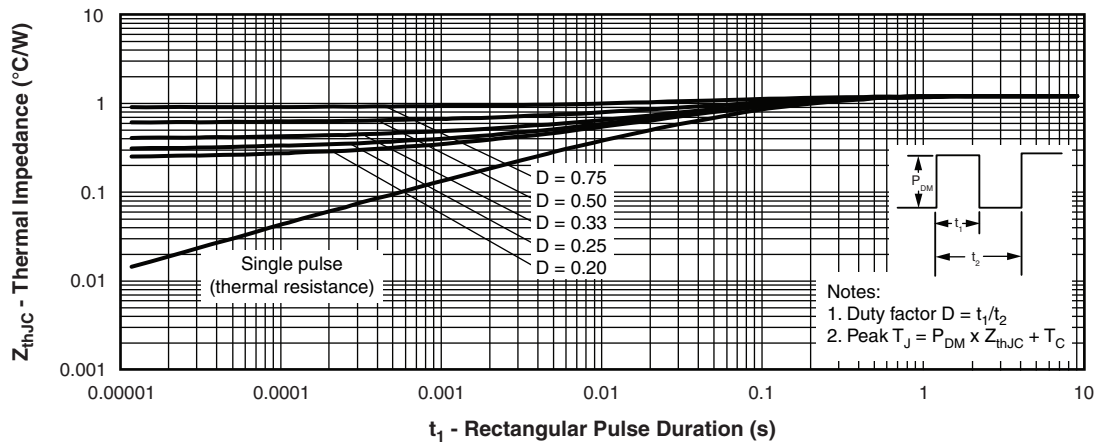


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

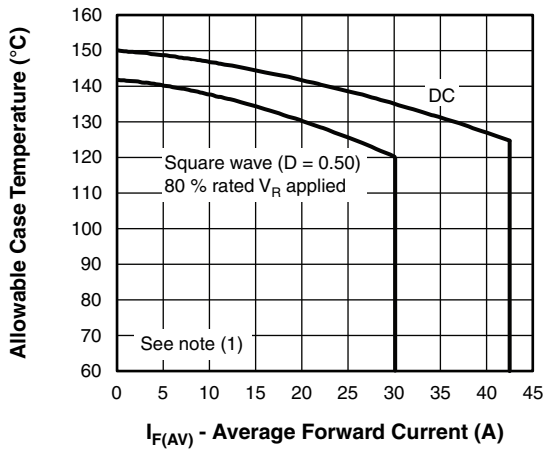


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

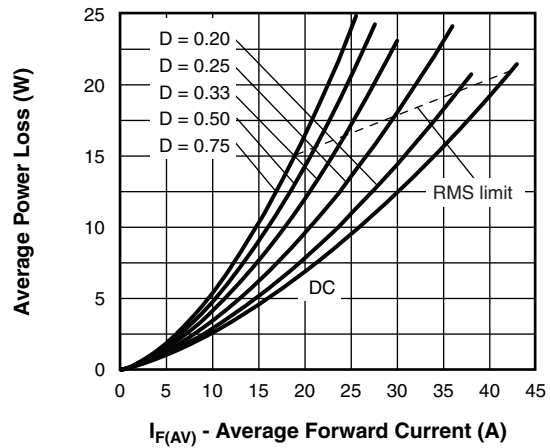


Fig. 6 - Forward Power Loss Characteristics

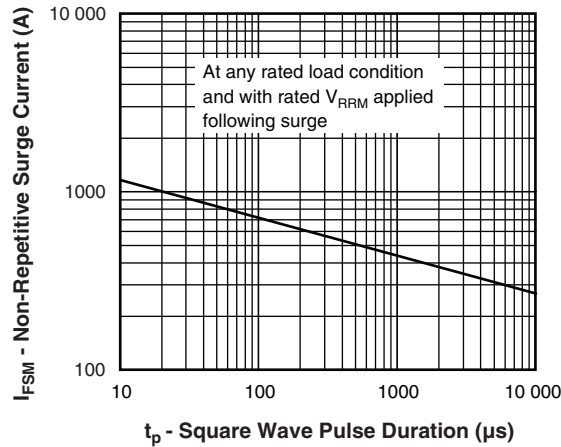


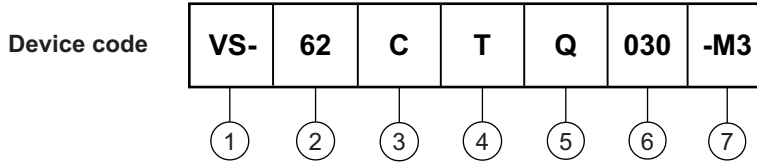
Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (60 = 60 A)
- 3** - Circuit configuration
C = Common cathode
- 4** - Package
T = TO-220
- 5** - Schottky "Q" series
- 6** - Voltage rating (030 = 30 V)
- 7** - Environmental digit
-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-62CTQ030-M3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96154
Part marking information	www.vishay.com/doc?95028
SPIICE model	www.vishay.com/doc?95185



3L TO-220AB

DIMENSIONS in millimeters and inches



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183		D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055		E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115		E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040		e	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4	e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068		H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4	L	13.52	14.02	0.532	0.552	
c	0.36	0.61	0.014	0.024		L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4	∅ P	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3	Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355							

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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